

# *Phase field simulations for grain growth and thermal grooving in thin films*

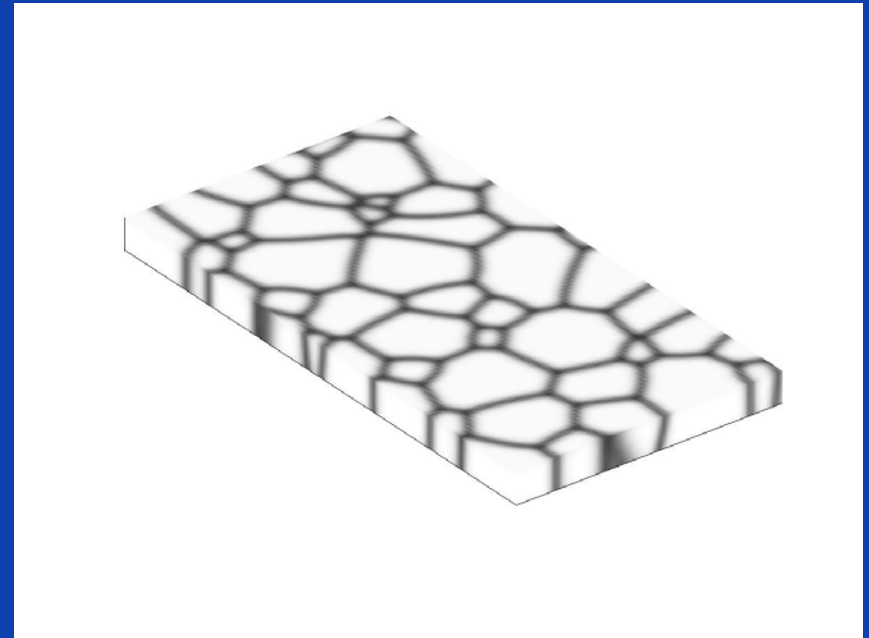
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**Research group: Thermodynamics in materials engineering**

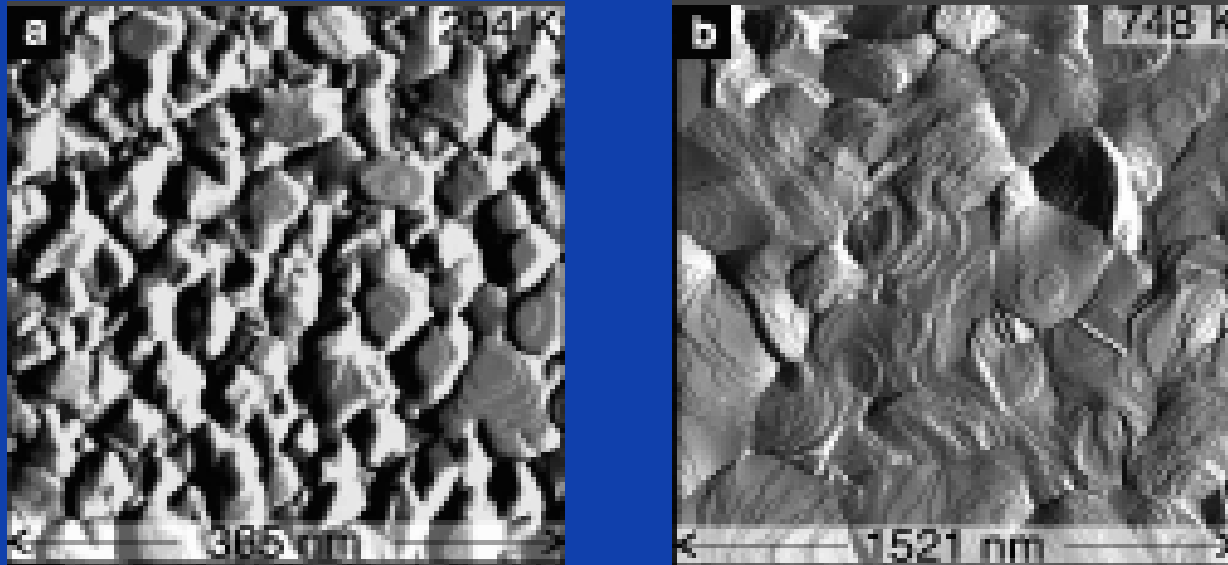
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- **Introduction on grain growth in thin films**
- **Phase field model**
- **Discussion of simulation results**
- **Outlook + conclusions**

- **Bamboo or columnar grain structure**
  - => 2-D grain growth
  
- **3-D effects**
  - Surface energy
  - Film-substrate interactions
  - Pinning precipitates



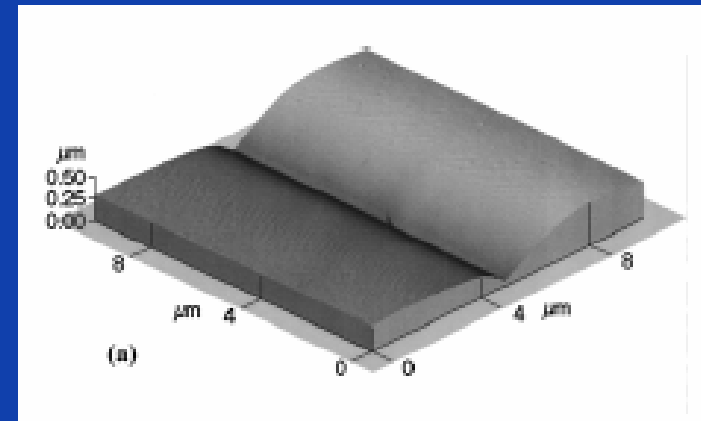
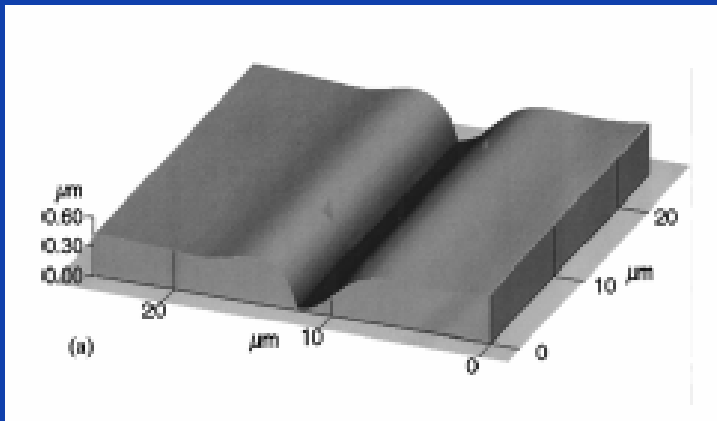
- Drag effect due to thermal grooving



*In-situ STM image for a gold film (Rost et al. 2003)*

- Abnormal grain growth induced by orientation dependence of surface energy  
=> huge grain size

- Different mechanisms for groove formation (Mullins 1957, Zhang 2004)
    - Volume diffusion
    - Surface diffusion
    - Evaporation-condensation
- ⇒ groove morphology during steady-state growth



*AFM image for a NiAl-alloy film (Klinger and Rabkin 2001)*

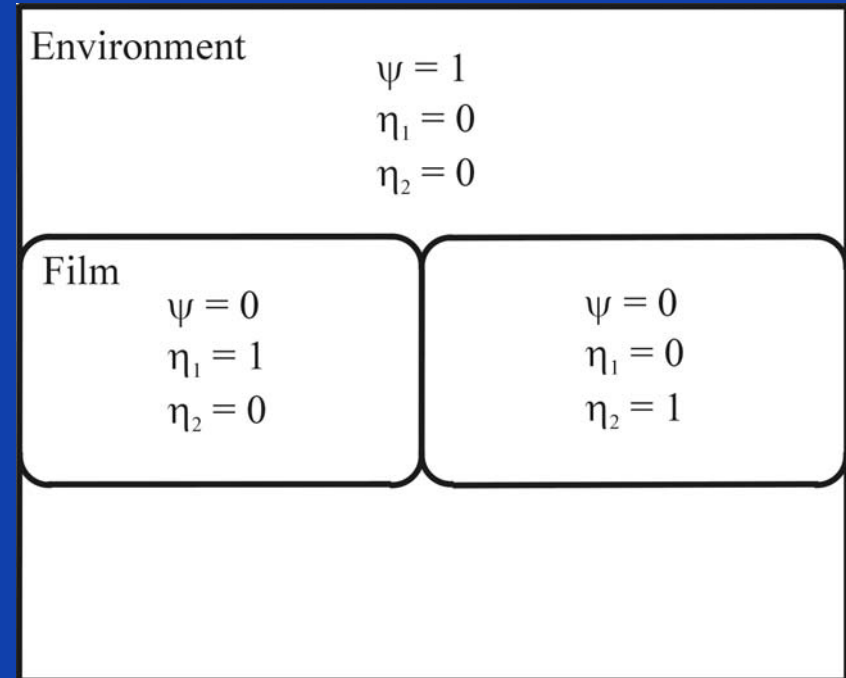
- **Simulation system**
  - Polycrystalline film
  - Environment, e.g. atmosphere, film substrate
- **Phase field variables**
  - Grain orientations (Chen1994, Fan1997)

$$\eta_1, \eta_2, \dots, \eta_i(\vec{r}, t), \dots, \eta_p$$

- Environment  $\psi(\vec{r}, t)$

- Scaled composition variable

$$\psi = \frac{c - c_{film}}{c_{env} - c_{film}}$$



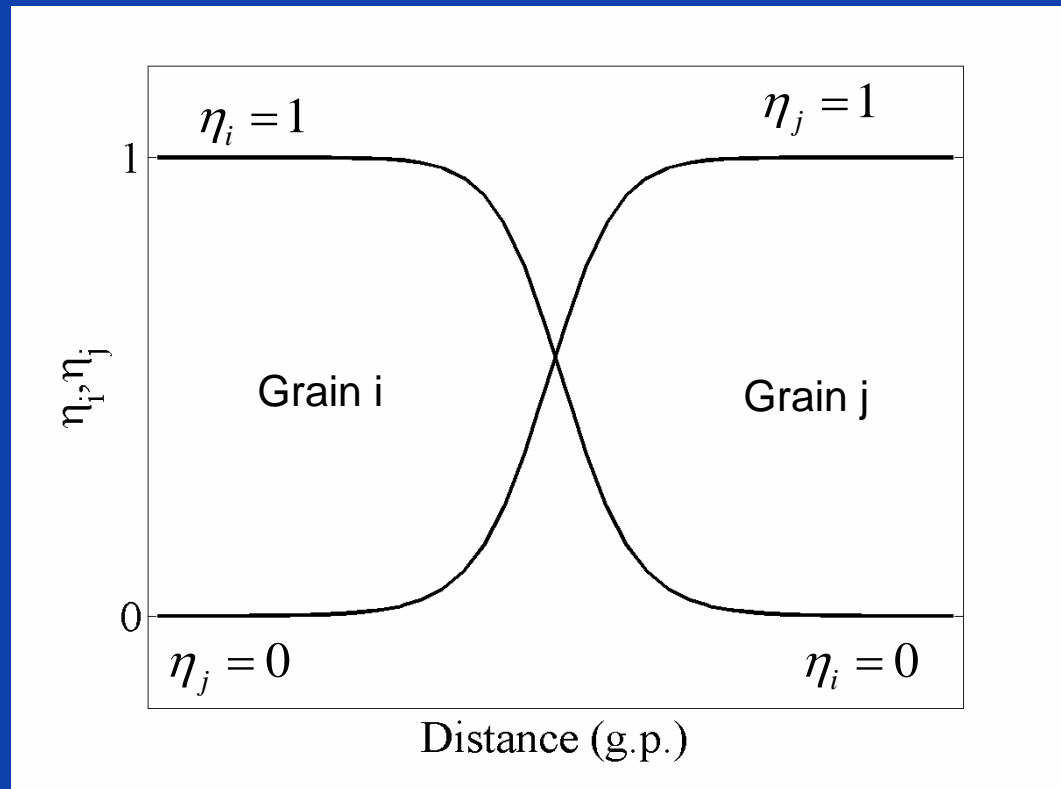
- Representation of an interface

- Grain boundary between grain i and grain j:

$$\eta_i^2 \eta_j^2 \neq 0$$

- Surface of grain i:

$$\eta_i^2 \psi^2 \neq 0$$



- Free energy

$$F = \int_V \left[ f_0(\eta_1, \eta_2, \dots, \eta_p, \psi) + \frac{\kappa}{2} \sum_{i=1}^p (\nabla \eta_i)^2 + \frac{\kappa}{2} \sum_{i=1}^p (\nabla \psi)^2 \right] dV$$

With

$$f_0 = m \left( \sum_{i=1}^p \left( \frac{\eta_i^4}{4} - \frac{\eta_i^2}{2} \right) + \left( \frac{\psi^4}{4} - \frac{\psi^2}{2} \right) + \sum_{i=1}^p \sum_{j<i}^p \gamma_{i,j} \eta_i^2 \eta_j^2 + \sum_{i=1}^p \gamma_{i,\psi} \eta_i^2 \psi^2 \right)$$

- Orientation dependence of surface energy

$$\gamma_{i,j}, \gamma_{i,\psi}$$

and

$$\kappa = \frac{\sum_{i=1}^p \sum_{j<i}^p \kappa_{i,j} \eta_i^2 \eta_j^2 + \sum_{i=1}^p \kappa_{i,\psi} \eta_i^2 \psi^2}{\sum_{i=1}^p \sum_{j<i}^p \eta_i^2 \eta_j^2 + \sum_{i=1}^p \eta_i^2 \psi^2}$$

$$F = \int_V \left[ f_0(\eta_1, \eta_2, \dots, \eta_p, \psi) + \frac{\kappa}{2} \sum_{i=1}^p (\nabla \eta_i)^2 + \frac{\kappa}{2} \sum_{i=1}^p (\nabla \psi)^2 \right] dV$$

$$f_0 = m \left( \sum_{i=1}^p \left( \frac{\eta_i^4}{4} - \frac{\eta_i^2}{2} \right) + \left( \frac{\psi^4}{4} - \frac{\psi^2}{2} \right) + \sum_{i=1}^p \sum_{j<i}^p \gamma_{i,j} \eta_i^2 \eta_j^2 + \sum_{i=1}^p \gamma_{i,\psi} \eta_i^2 \psi^2 \right)$$

- **Interfacial energy**

$$\sigma_{i,j} = \frac{1}{\sqrt{3}} \sqrt{m \kappa_{i,j} (1 + 2\gamma_{i,j})}$$

- **Interfacial width**

$$l_{i,j} \propto \sqrt{\frac{32\kappa_{i,j}}{m(1 + 2\gamma_{i,j})}}$$

- Temporal evolution  $\eta_i$

$$\frac{\partial \eta_i(\mathbf{r}, t)}{\partial t} = -L \frac{\partial F(\eta_1, \dots, \eta_p, \psi)}{\partial \eta_i(\mathbf{r}, t)}$$

- Temporal evolution  $\psi$

$$\frac{\partial \psi(\mathbf{r}, t)}{\partial t} = \nabla \cdot M \nabla \frac{\partial F(\eta_1, \dots, \eta_p, \psi)}{\partial \psi(\mathbf{r}, t)}$$

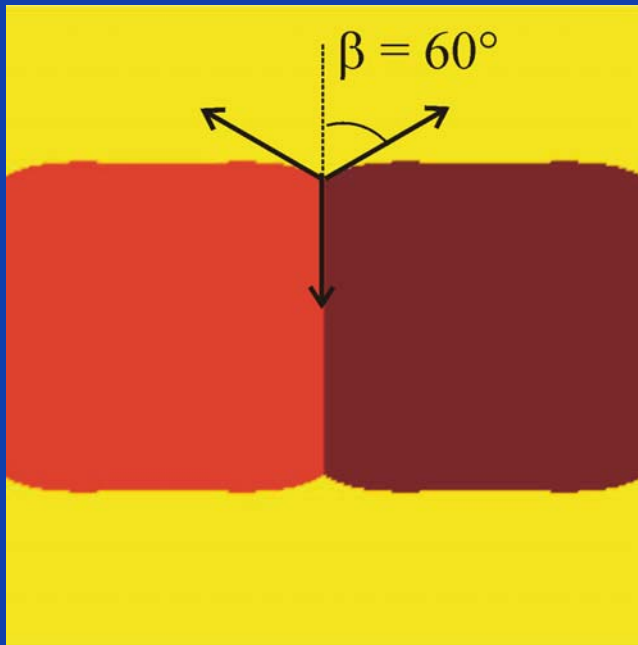
- Bulk versus interface diffusion

$$M = \frac{M_{film} \left( \sum_{i=1}^p \eta_i^2 \right) + M_{env} \psi^2}{\sum_{i=1}^p \eta_i^2 + \psi^2} \quad \text{for} \quad \sum_{i=1}^p \sum_{j<i}^p \eta_i^2 \eta_j^2 + \sum_{i=1}^p \eta_i^2 \psi^2 < 10e-6$$

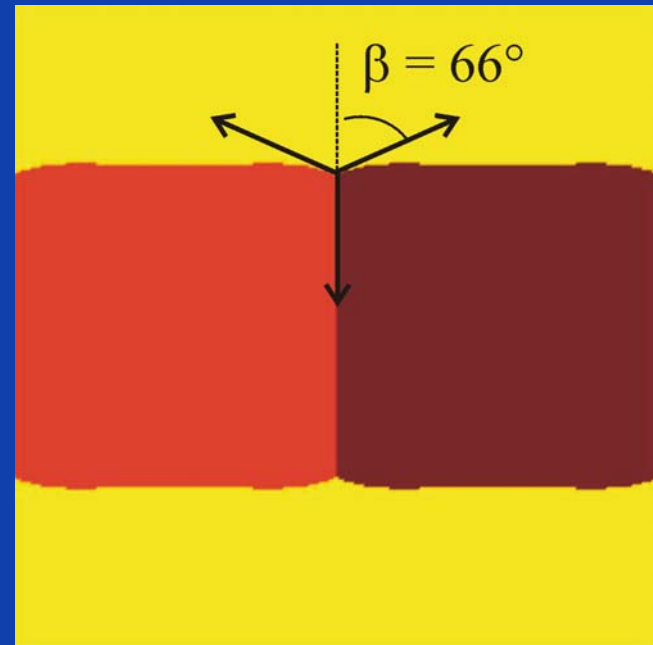
$$M = \frac{M_{gb} \left( \sum_{i=1}^p \sum_{j<i}^p \eta_i^2 \eta_j^2 \right) + M_{surf} \sum_{i=1}^p \eta_i^2 \psi^2}{\sum_{i=1}^p \sum_{j<i}^p \eta_i^2 \eta_j^2 + \sum_{i=1}^p \eta_i^2 \psi^2} \quad \text{for} \quad \sum_{i=1}^p \sum_{j<i}^p \eta_i^2 \eta_j^2 + \sum_{i=1}^p \eta_i^2 \psi^2 > 10e-6$$

- Grain boundary versus surface energy:

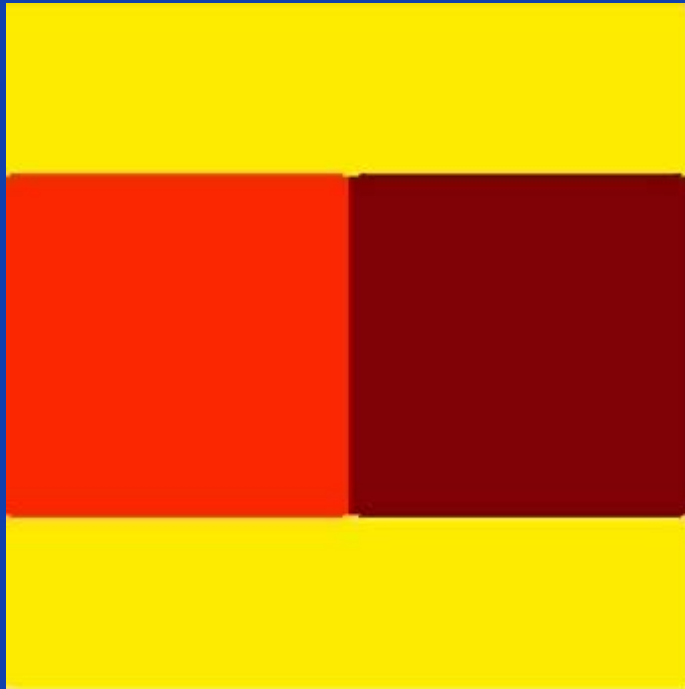
$$\sigma_{gb} = 2\sigma_{surf} \cos(\beta)$$



$$\sigma_{surf} = \sigma_{gb}$$



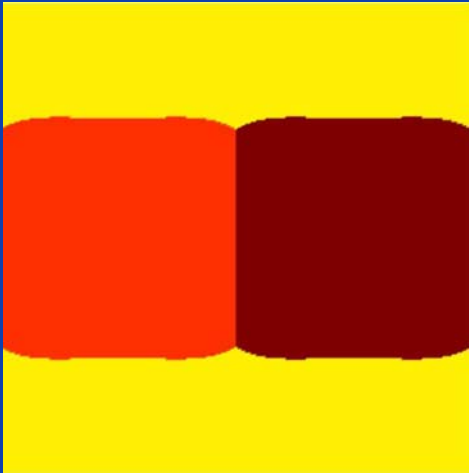
$$\sigma_{surf} = (5/4)\sigma_{gb}$$



$$\sigma_{surf,2} = (5/4)\sigma_{surf,1}$$

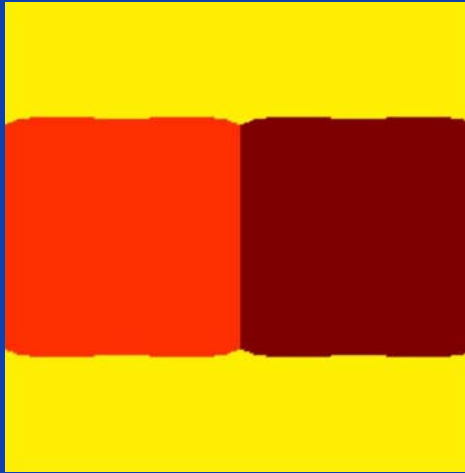
- Columnar grain boundary becomes curved to balance unequal surface tensions
- Grain boundary migration towards center of curvature
- => favourably oriented grain grows

- Bulk diffusion



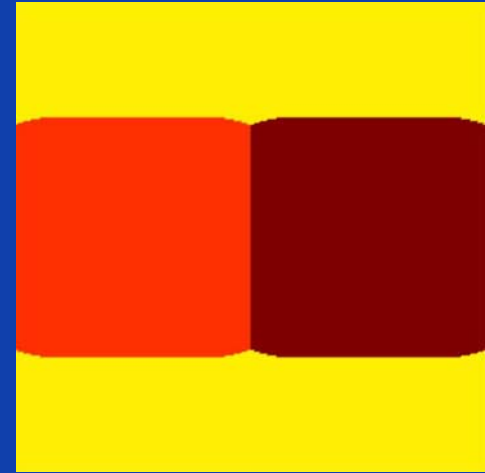
$M = \text{cte}$   
solubility  $\approx 0$

- Surface diffusion



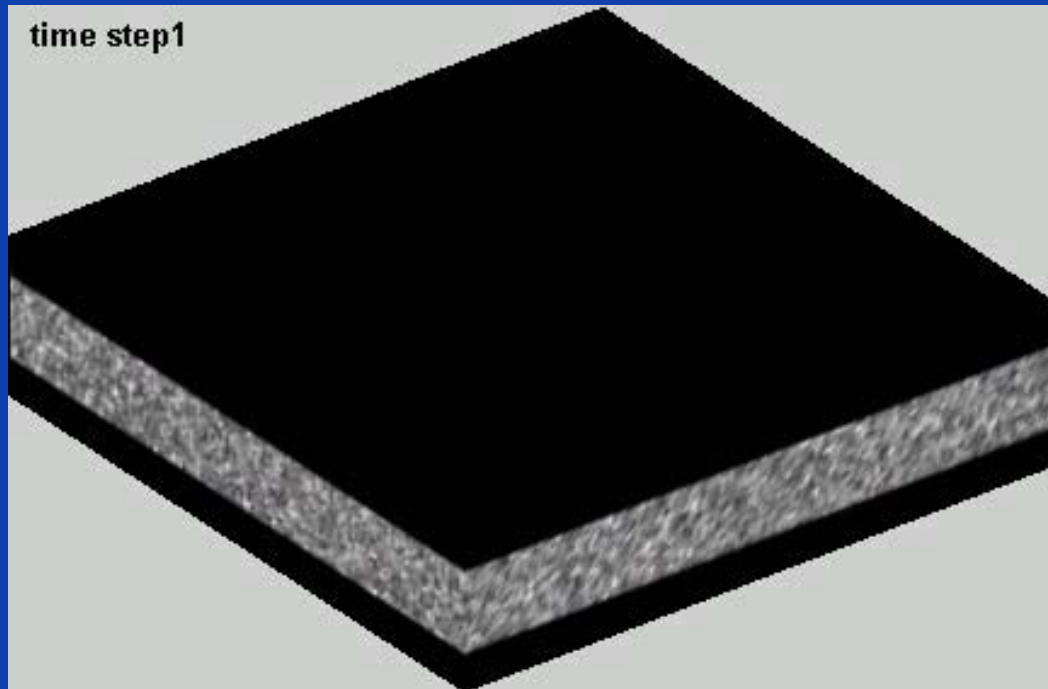
$M_{\text{surf}} = 1$   
solubility  $\approx 0$   
 $M_{\text{film}} = M_{\text{env}} = M_{\text{gb}} = 0$

- Evaporation-condensation

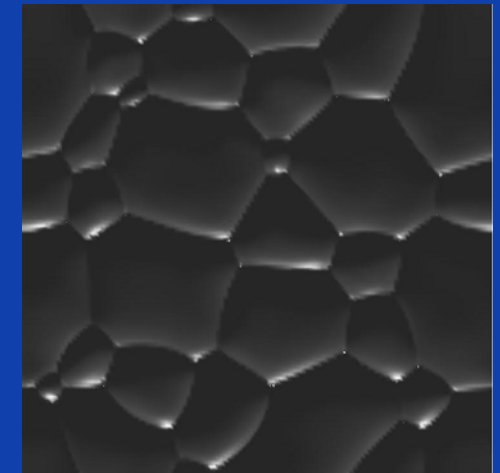


$M_{\text{env}} = M_{\text{surf}} = 1$   
solubility = 0.0001  
 $M_{\text{film}} = M_{\text{gb}} = 0$

- 3-D simulations for polycrystalline films



*Efficient implementation for  $\kappa$  and  $M$  constant*



*Top view*

- **Phase field model for grain growth and grooving in thin films**
  - Simulation system includes film + environment
  - Orientation dependent surface energy and misorientation dependent grain boundary energy
  - Bulk and interfacial diffusion can be distinguished
  
- **More information about my research:**  
<http://www.ulyssis.org/~nele/>
  
- *Acknowledgements: This research was funded by the Institute for the Promotion of Innovation through Science and Technology in Flanders (IWT-Vlaanderen).*